



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

CPH6347 — P-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- 1.8V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-20	V
Gate-to-Source Voltage	V _{GSS}		±12	V
Drain Current (DC)	I _D		-6	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-24	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (900mm ² ×0.8mm)	1.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _{GS} =0V	-20			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-0.4		-1.4	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-3A	4.3	7.3		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-3A, V _{GS} =-4.5V		30	39	mΩ
	R _{DS(on)2}	I _D =-1.5A, V _{GS} =-2.5V		44	66	mΩ
	R _{DS(on)3}	I _D =-0.6A, V _{GS} =-1.8V		68	102	mΩ

Marking : YZ

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CPH6347

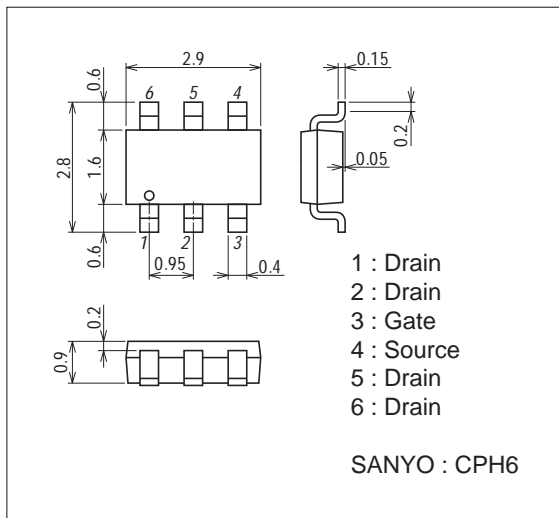
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS} = -10V, f = 1MHz$		860		pF
Output Capacitance	Coss	$V_{DS} = -10V, f = 1MHz$		170		pF
Reverse Transfer Capacitance	Crss	$V_{DS} = -10V, f = 1MHz$		130		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		10		ns
Rise Time	t_r	See specified Test Circuit.		48		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit.		100		ns
Fall Time	t_f	See specified Test Circuit.		78		ns
Total Gate Charge	Qg	$V_{DS} = -10V, V_{GS} = -4.5V, I_D = -6A$		10.5		nC
Gate-to-Source Charge	Qgs	$V_{DS} = -10V, V_{GS} = -4.5V, I_D = -6A$		2.0		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS} = -10V, V_{GS} = -4.5V, I_D = -6A$		3.0		nC
Diode Forward Voltage	VSD	$I_S = -6A, V_{GS} = 0V$		-0.82	-1.5	V

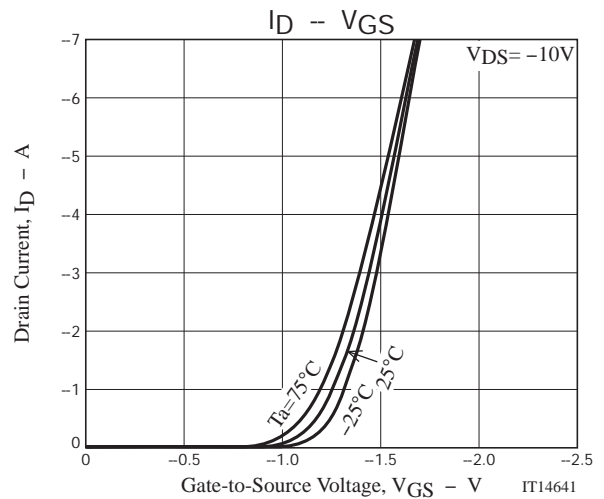
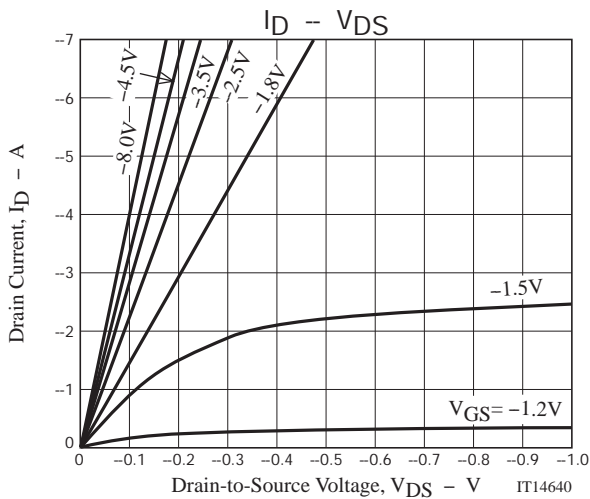
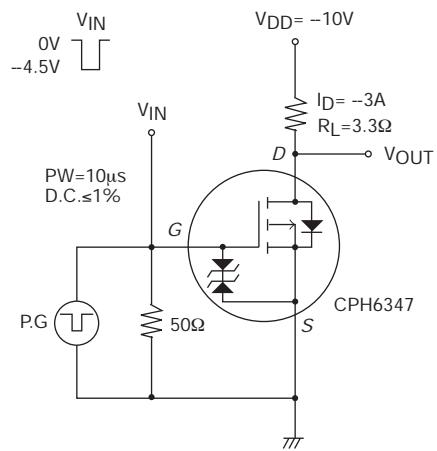
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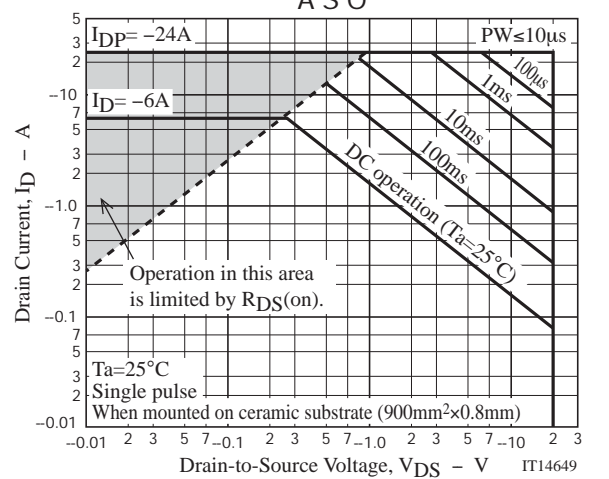
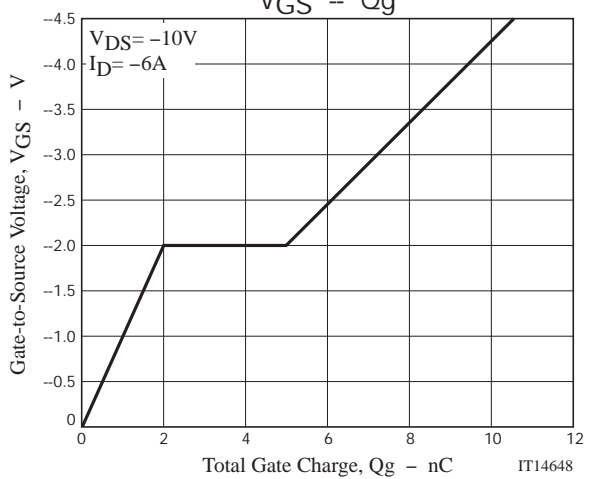
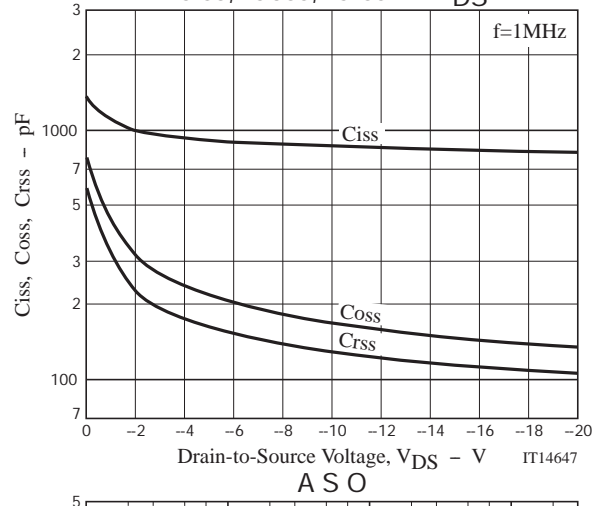
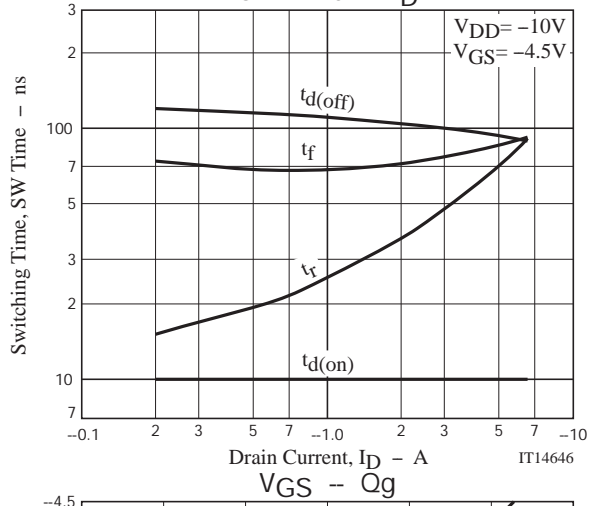
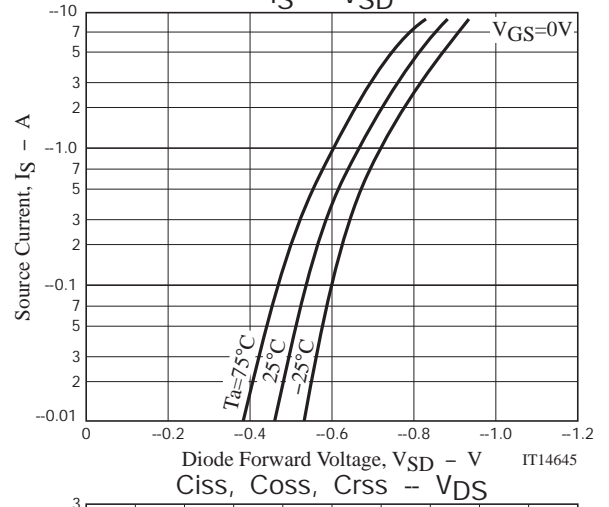
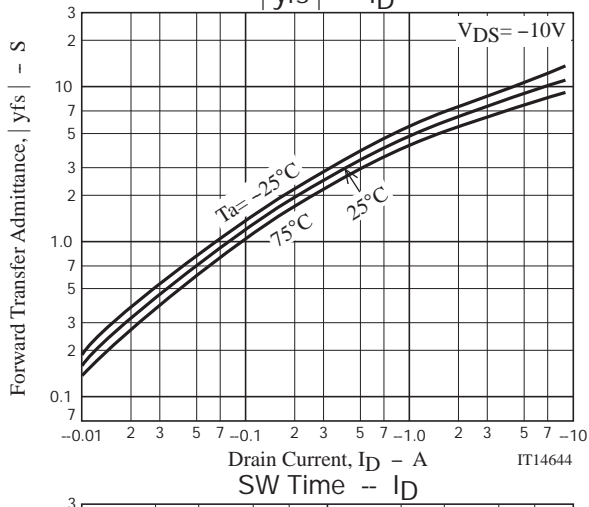
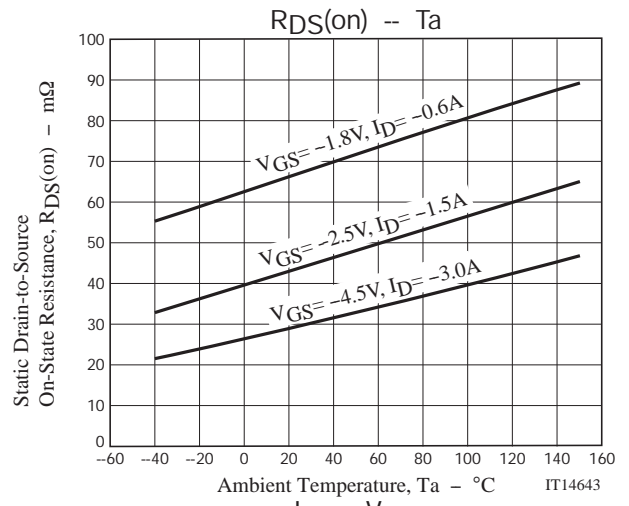
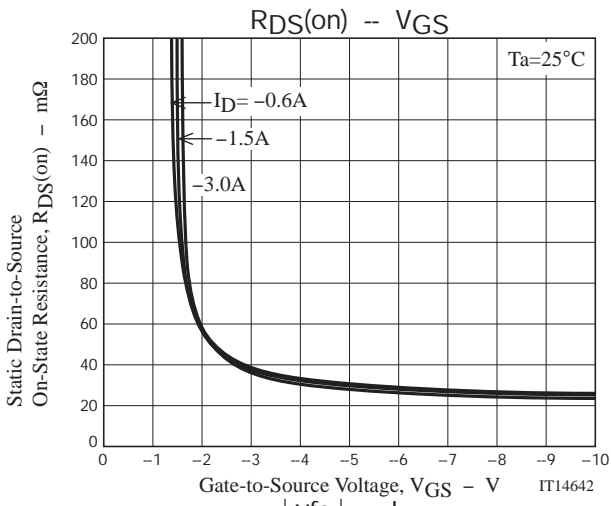
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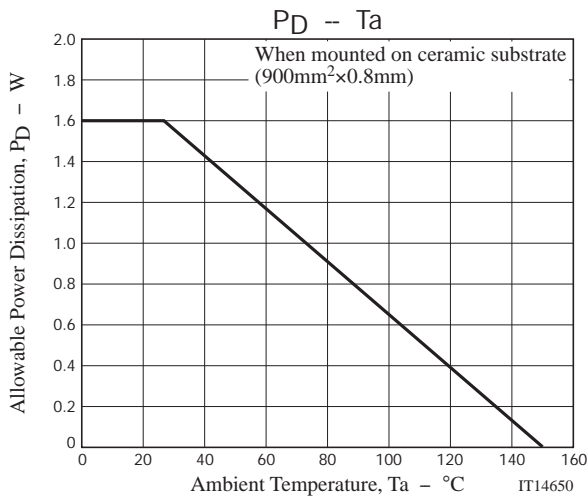
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Switching Time Test Circuit







Note on usage : Since the CPH6347 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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